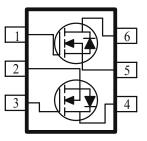
N-Channel 30-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low $r_{DS(on)}$ and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

- Low r_{DS(on)} provides higher efficiency and extends battery life
- Low thermal impedance copper leadframe TSOP-6 saves board space
- Fast switching speed
- High performance trench technology

| PRODUCT SUMMARY | | | | |
|---------------------|---------------------------------|--------------------|--|--|
| V _{DS} (V) | $r_{\mathrm{DS(on)}} m(\Omega)$ | I _D (A) | | |
| 30 | $63 @ V_{GS} = 4.5V$ | 3.5 | | |
| | $110 @ V_{GS} = 2.5V$ | 3.0 | | |





| ABSOLUTE MAXIMUM RATINGS ($T_A = 25$ °C UNLESS OTHERWISE NOTED) | | | | | | |
|--|---|-----------------------------------|------------|----|--|--|
| Parameter | Symbol | Limit | Units | | | |
| Drain-Source Voltage | | | 30 | v | | |
| Gate-Source Voltage | | | ±12 | v | | |
| Continuous Drain Current ^a | T _A =25°C | J. | 3.5 | А | | |
| Continuous Drain Current | $T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$ | ID | 2.8 | | | |
| Pulsed Drain Current ^b | | | 16 | | | |
| Continuous Source Current (Diode Conduction) ^a | | Is | 1.25 | А | | |
| Power Dissipation ^a | $T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$ | P _D | 1.3 | W | | |
| Power Dissipation | $T_A=70^{\circ}C$ | тD | 0.8 | ** | | |
| Operating Junction and Storage Temperature Range | | T _J , T _{stg} | -55 to 150 | °C | | |

| THERMAL RESISTANCE RATINGS | | | | | | |
|--|--------------|-----------------|---------|-------|--|--|
| Parameter | | Symbol | Maximum | Units | | |
| | t <= 10 sec | Л | 100 | °C/W | | |
| Maximum Junction-to-Ambient ^a | Steady-State | $R_{\theta JA}$ | 166 | °C/W | | |

Notes

a. Surface Mounted on 1" x 1" FR4 Board.

b. Pulse width limited by maximum junction temperature

1

| SPECIFICATIONS ($T_A = 25^{\circ}C$ UNLESS OTHERWISE NOTED) | | | | | | | |
|--|---------------------|--|--------|-------------|---------|--------|--|
| Democratica | C | | Limits | | | TT . 4 | |
| Parameter | Symbol | Test Conditions | Min | Min Typ Max | | Unit | |
| Static | | | | | | | |
| Gate-Threshold Voltage | V _{GS(th)} | $V_{DS} = V_{GS}, I_D = 250 \text{ uA}$ | 0.7 | | | V | |
| Gate-Body Leakage | I _{GSS} | $V_{DS} = 0 V, V_{GS} = 12 V$ | | | ±100 | nA | |
| Zero Gate Voltage Drain Current | I _{DSS} | $V_{DS} = 24 V, V_{GS} = 0 V$ $V_{DS} = 24 V, V_{GS} = 0 V, T_J = 55^{\circ}C$ | | | 1 25 | uA | |
| On-State Drain Current ^A | I _{D(on)} | $V_{DS} = 5 V, V_{GS} = 4.5 V$ | 6 | | | А | |
| Drain-Source On-Resistance ^A | r _{DS(on)} | $V_{GS} = 4.5 \text{ V}, I_D = 3.5 \text{ A}$ | | | 63 | mΩ | |
| | ¹ DS(00) | $V_{GS} = 2.5 \text{ V}, I_D = 3 \text{ A}$ | | | 110 | 1112.2 | |
| Forward Tranconductance ^A | $g_{\rm fs}$ | $V_{DS} = 15 \text{ V}, I_D = 3.5 \text{ A}$ | | 6.9 | | S | |
| Diode Forward Voltage | V _{SD} | $I_{\rm S} = 2.3$ A, $V_{\rm GS} = 0$ V | | 0.8 | | V | |
| Dynamic ^b | | | | | | | |
| Total Gate Charge | Qg | $V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V},$ $I_D = 3.5 \text{ A}$ | | 6.3 | | nC | |
| Gate-Source Charge | Q _{gs} | | | 0.9 | | | |
| Gate-Drain Charge | Q _{gd} | | | 1.9 | |] | |
| Input Capacitance | C _{iss} | | | 265 | | | |
| Output Capacitance | C _{oss} | $V_{DS} = 15 V, V_{GS} = 0 V, f = 1 MHz$ | | 54 | | pF | |
| Reverse Transfer Capacitance | C _{rss} | | | 24 | | | |
| Turn-On Delay Time | t _{d(on)} | | | 16 | | | |
| Rise Time | t _r | $V_{DD} = 25 \text{ V}, \text{R}_{\text{L}} = 25 \Omega , \text{I}\text{D} = 1 \text{ A},$ | | 5 | | nS | |
| Turn-Off Delay Time | t _{d(off)} | $V_{GEN} = 10 V$ | | 23 | | 115 | |
| Fall-Time | t _f | | | 3 | | | |

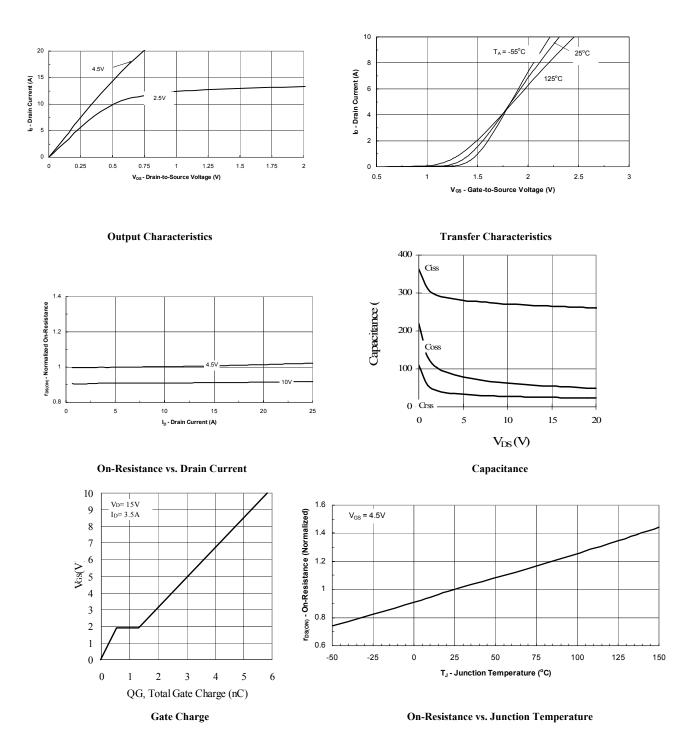
Notes

a. Pulse test: $PW \le 300$ uty cycle $\le 2\%$.

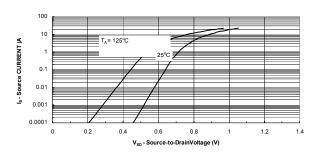
b. Guaranteed by design, not subject to production testing.

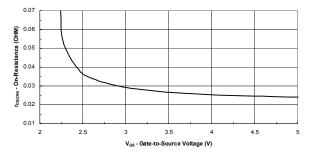
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Typical Electrical Characteristics (N-Channel)



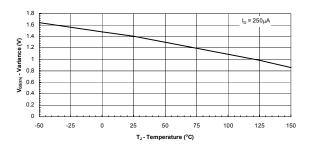
Typical Electrical Characteristics (N-Channel)

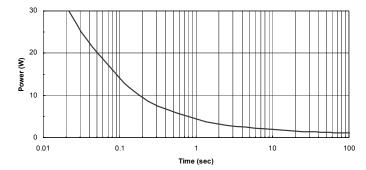


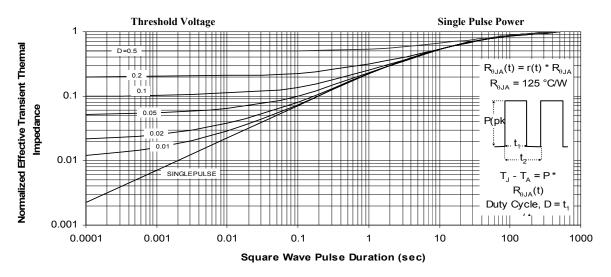


Source-Drain Diode Forward Voltage

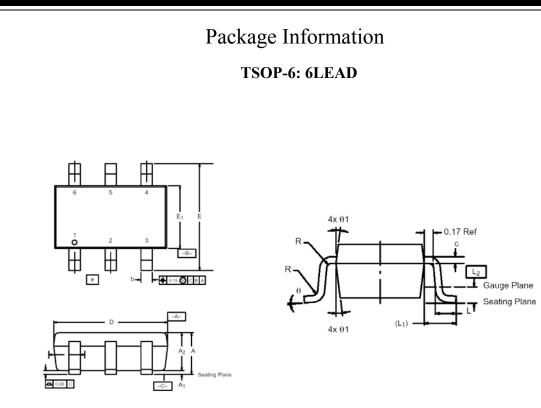
On-Resistance vs.Gate-to Source Voltage







Normalized Thermal Transient Impedance, Junction-to-Ambient



| | MILLIMETERS | | | INCHES | | | |
|----------------|-------------|------|------|------------|-------|-------|--|
| Dim | Min | Nom | Max | Min | Nom | Max | |
| Α | 0.91 | - | 1.10 | 0.036 | - | 0.043 | |
| A ₁ | 0.01 | - | 0.10 | 0.0004 | - | 0.004 | |
| A ₂ | 0.84 | - | 1.00 | 0.033 | 0.038 | 0.039 | |
| b | 0.30 | 0.32 | 0.45 | 0.012 | 0.013 | 0.018 | |
| С | 0.10 | 0.15 | 0.20 | 0.004 | 0.006 | 0.008 | |
| D | 2.95 | 3.05 | 3.10 | 0.116 | 0.120 | 0.122 | |
| E | 2.70 | 2.85 | 2.98 | 0.106 | 0.112 | 0.117 | |
| E ₁ | 1.55 | 1.65 | 1.70 | 0.061 | 0.065 | 0.067 | |
| е | 1.00 BSC | | | 0.0394 BSC | | | |
| L | 0.35 | - | 0.50 | 0.014 | - | 0.020 | |
| L ₁ | 0.60 Ref | | | 0.024 Ref | | | |
| L ₂ | 0.25 BSC | | | 0.010 BSC | | | |
| R | 0.10 | - | - | 0.004 | - | _ | |
| θ | 0° | 4° | 8° | 0° | 4° | 8° | |
| θ_1 | 7° Nom | | | 7° Nom | | | |